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Serial No. ~~not yet assigned~~ 101670485 Examiner: ~~not yet assigned~~ NGUYEN, T.T.

Title: BOTTOM ELECTRODE OF CAPACITOR OF SEMICONDUCTOR DEVICE AND METHOD OF FORMING THE SAME

INFORMATION DISCLOSURE CITATION  
FORM PTO-1449 (Modified)

U.S. PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Issue</u> <u>Date</u>	<u>Name</u>	<u>Class</u>	<u>Sub</u> <u>Class</u>
TN	_____	6,080,620	6/27/200	Jeng	—	—
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<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Publication</u> <u>Date</u>	<u>Country</u>	<u>Name</u>
TN	_____	JP2001-57413	2/27/2001	Japan	Kenichi et al.

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<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
TN	_____	English language of Japanese Patent Publication No. 2001-57413, filed February 2, 2001.

Examiner: Tham

Date Considered: 9/14/04

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